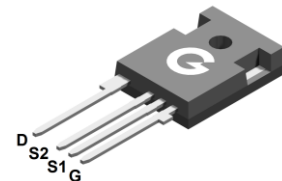
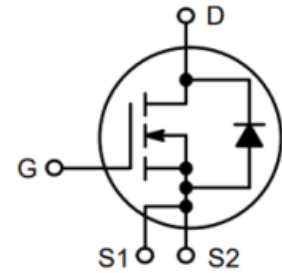


Features

- High blocking voltage with low on-resistance
- High-speed switching with low capacitances
- Low Switching Losses
- Sense pin for optimized switching performance
- RoHS compliant with Halogen-free

HF



TO-247-4L

Applications

- Solar inverters
- Charger
- Uninterruptible Power Supply
- Switch Mode Power Supplies

Mechanical Data

- Case: TO-247-4L
- Molding Compound: UL Flammability Classification Rating 94V-0
- Terminals: Matte tin-plated leads; solderability-per MIL-STD-202, Method 208

Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
GSC170R022U4	TO-247-4L	30 pcs / Tube	GSC170R022U4

Maximum Ratings (@ T_C = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-to-Source Voltage	V _{DSS}	1700	V
Gate-to-Source Voltage (transient)	V _{GSS}	-8/+22	V
Gate-to-Source Voltage (static)		-4/+18	V
Continuous Drain Current (T _C = 25°C)	I _D	123	A
Continuous Drain Current (T _C = 100°C)		78	A
Pulsed Drain Current	I _{DM}	260	A
Power Dissipation (T _C = 25°C)	P _D	625	W
Operating Junction Temperature Range	T _J	-40 ~ +175	°C
Storage Temperature Range	T _{STG}	-40 ~ +175	°C

Thermal Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit
Thermal Resistance Junction-to-Case	R _{θJC}	-	0.24		°C/W

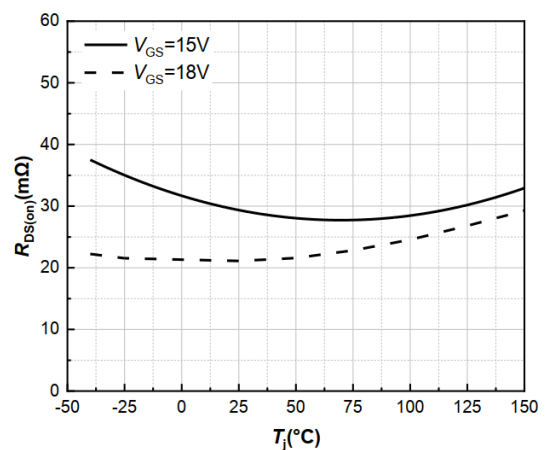
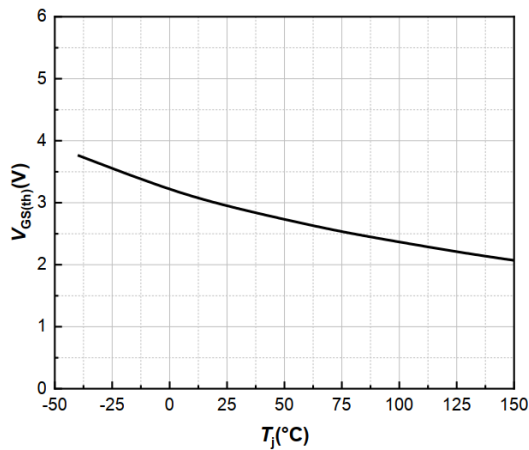
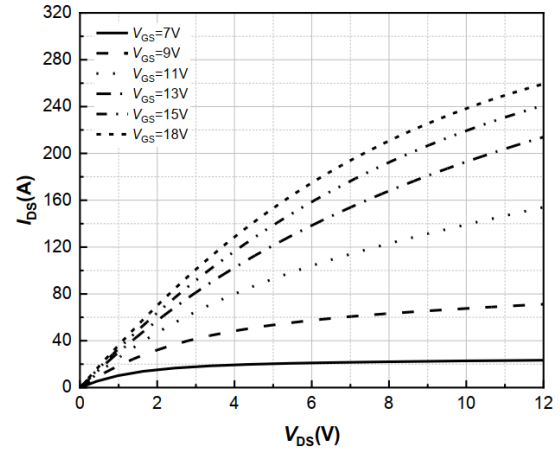
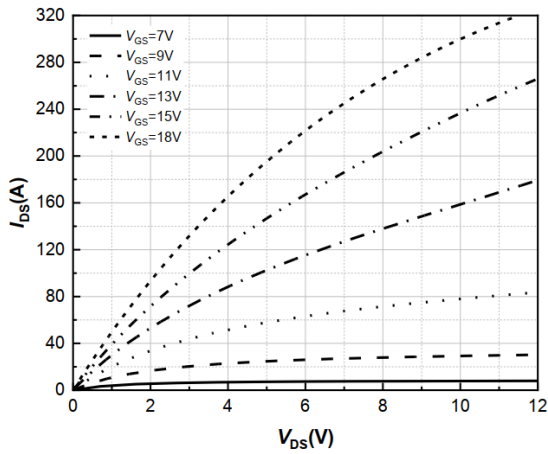
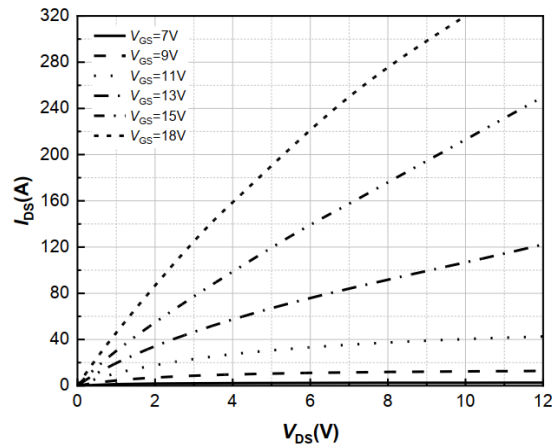
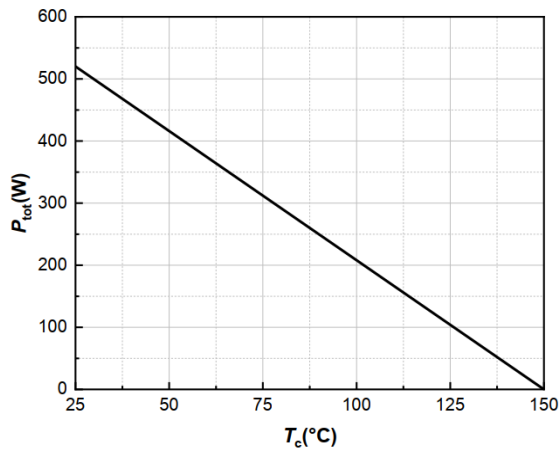
Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
V _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0V, I _D = 100μA	1700	-	-	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 1700V, V _{GS} = 0V	-	1	-	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} = 18V, V _{DS} = 0V	-	-	250	nA
		V _{GS} = -4V, V _{DS} = 0V	-	-	-100	nA
On Characteristics						
R _{DS(ON)}	Drain-Source On-resistance *1	V _{GS} = 18V, I _D = 80A, T _J = 25°C	-	22	-	mΩ
		V _{GS} = 18V, I _D = 80A, T _J = 150°C	-	30	-	
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = 20mA	2	-	4	V
R _G	Gate Resistance	V _{GS} = 0V, f = 1MHz	-	4.4	-	Ω
Dynamic Characteristics						
C _{ISS}	Input Capacitance	V _{DS} = 1200V V _{GS} = 0V f = 100kHz	-	5133	-	pF
C _{OSS}	Output Capacitance		-	187	-	
C _{RSS}	Reverse Transfer Capacitance		-	8	-	
Switching Characteristics						
t _{d(ON)}	Turn-on Delay Time *2	V _{DD} = 1200V V _{GS} = -4/18V I _D = 50A R _G = 2.5Ω	-	28	-	ns
t _r	Turn-on Rise Time *2		-	40	-	
t _{d(OFF)}	Turn-Off Delay Time *2		-	52	-	
t _f	Turn-Off Fall Time *2		-	19	-	
E _{on}	Turn-On Energy *2		-	1541	-	μJ
E _{off}	Turn-Off Energy *2		-	565	-	
Q _G	Total Gate-Charge	V _{DD} = 1200V	-	207	-	nC
Q _{GS}	Gate to Source Charge	V _{GS} = -4/18V	-	65	-	
Q _{GD}	Gate to Drain (Miller) Charge	I _D = 50A	-	49	-	
Source-Drain Diode Characteristics						
V _{SD}	Diode Forward Voltage *1	I _{SD} = 40A, V _{GS} = -4V, T _J = 25°C	-	4.4	-	V
		I _{SD} = 40A, V _{GS} = -4V, T _J = 150°C	-	3.9	-	
t _{rr}	Reverse Recovery Time	I _F = 50A, V _R = 1200V	-	16	-	ns
Q _{rr}	Reverse Recovery Charge	dI/dt = 3506A/μs	-	228	-	nC

Notes:

- The data tested by pulsed, pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$
- Guaranteed by design, not subject to production

Ratings and Characteristics Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)



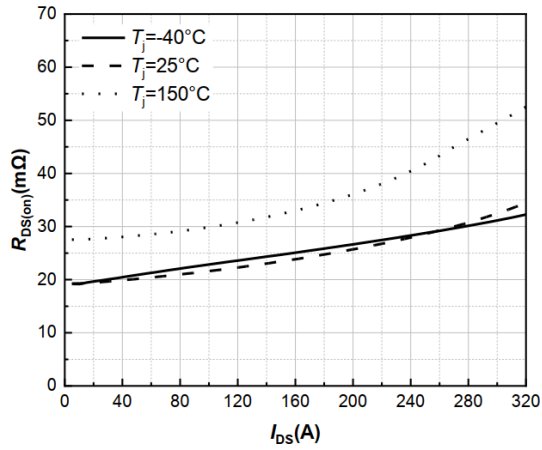


Fig 7 On-Resistance vs. Drain Current

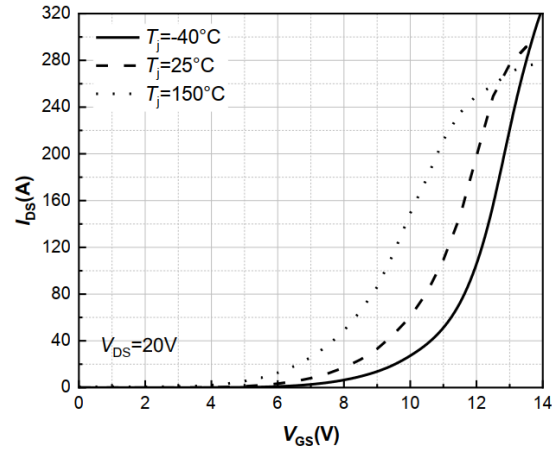


Fig 8 Transfer Characteristics

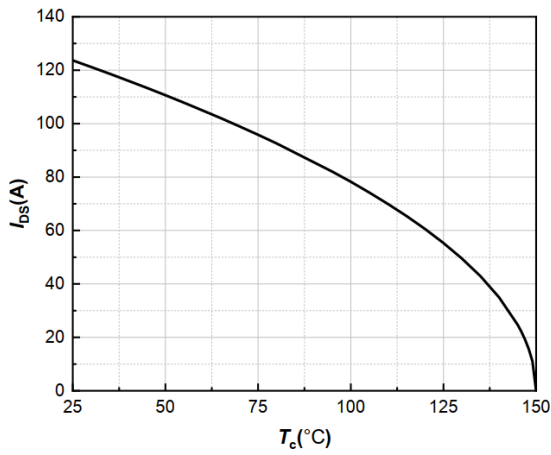


Fig 9 Diode Forward Voltage vs. Junction Temperature

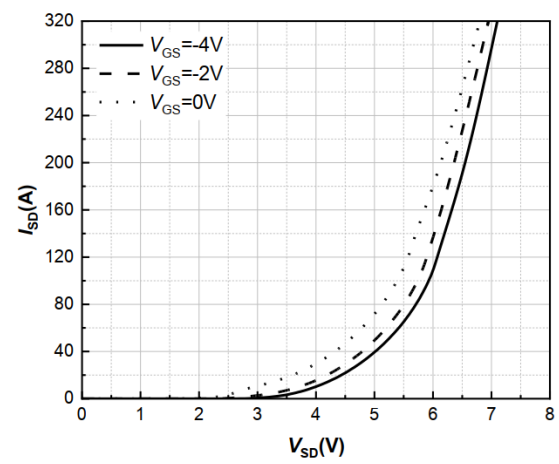


Fig 10 Body-Diode Characteristics ($T_J = -40^\circ\text{C}$)

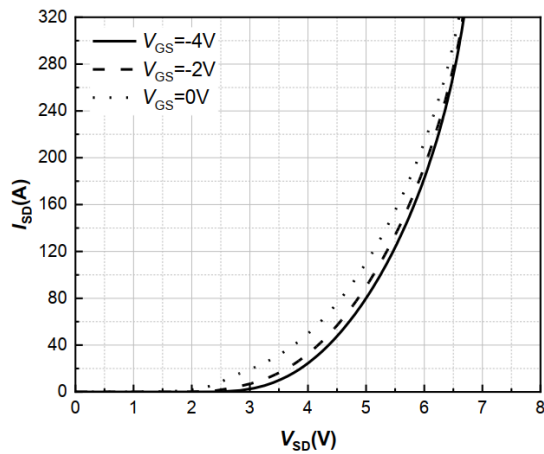


Fig 11 Body-Diode Characteristics ($T_J = 25^\circ\text{C}$)

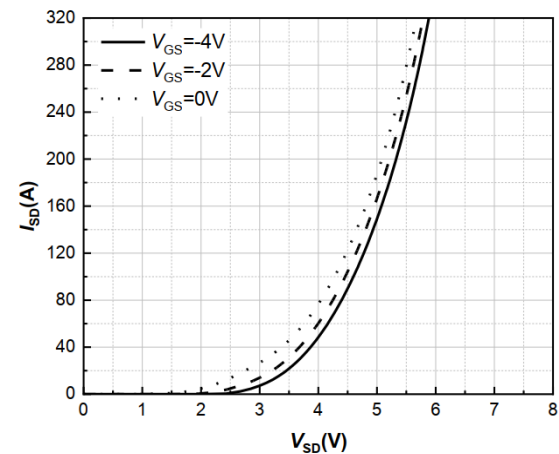


Fig 12 Body-Diode Characteristics ($T_J = 150^\circ\text{C}$)

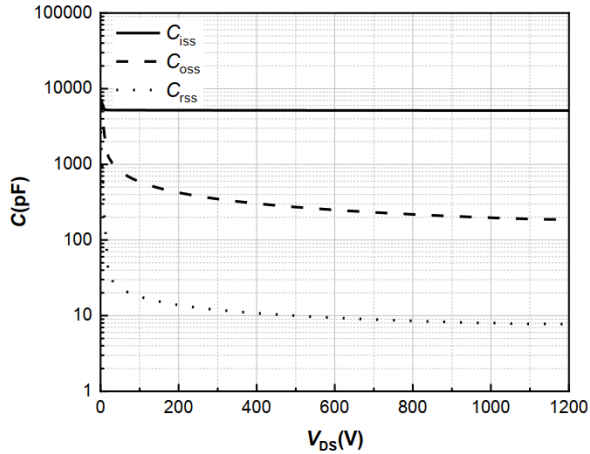


Fig 13 Capacitance Characteristics

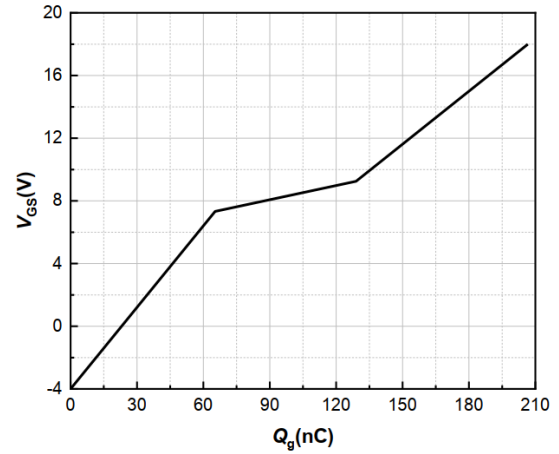


Fig 14 Gate-Charge Characteristics

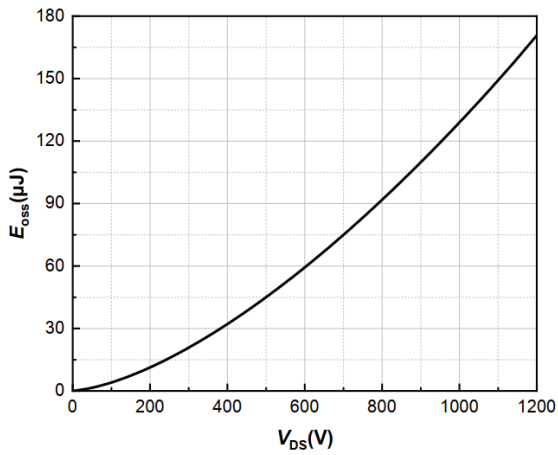


Fig 15 Output Capacitor Stored Energy

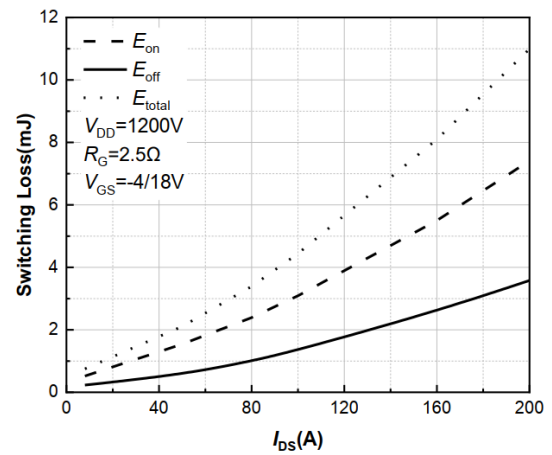


Fig 16 Clamped Inductive Switching Energy vs. Drain Current

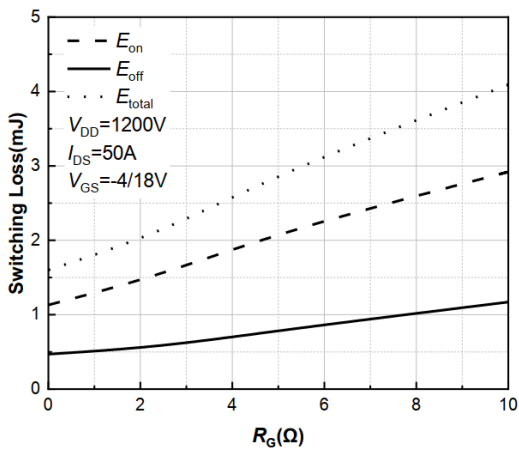


Fig 17 Clamped Inductive Switching Energy vs. R_G

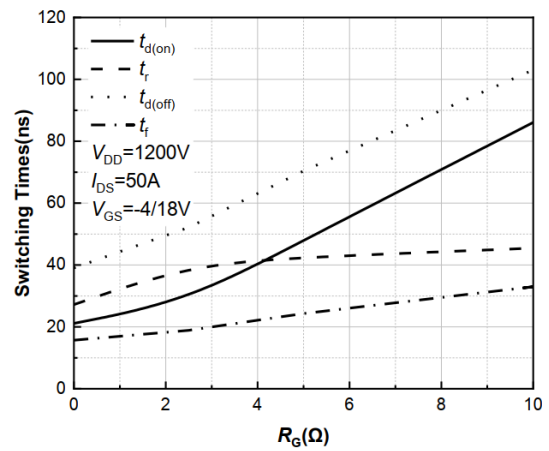


Fig 18 Switching Times vs. R_G

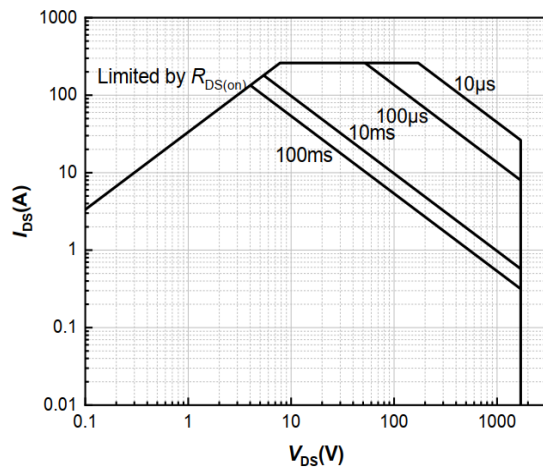


Fig 19 Safe Operating Area

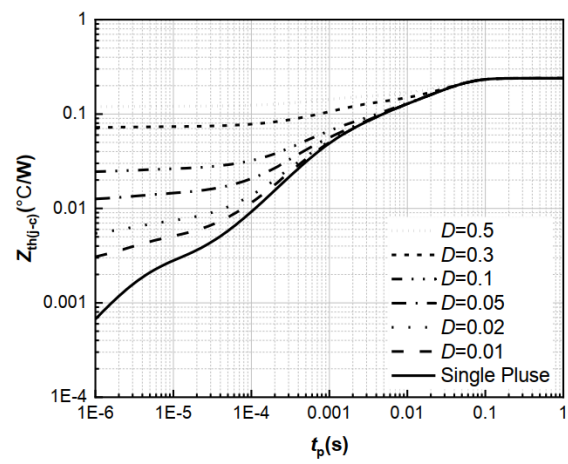
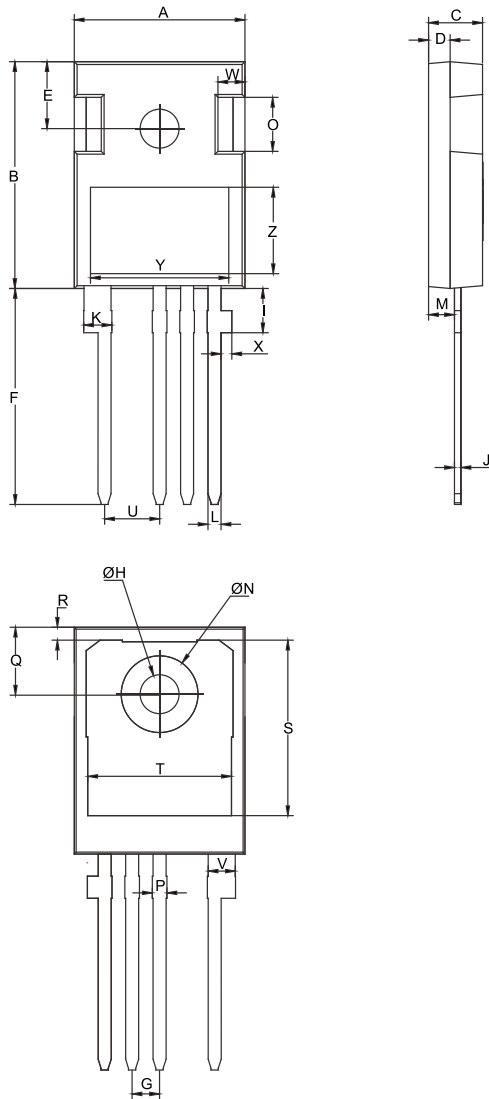


Fig 20 Maximum transient thermal impedance

Package Outline Dimensions (Unit: mm)



TO-247-4L		
Dimension	Min.	Max.
A	15.50	16.10
B	20.70	21.30
C	4.70	5.30
D	1.80	2.20
E	5.40	6.20
F	19.60	20.40
G	2.34	2.74
H	3.40	3.80
I	3.90	4.30
J	0.45	0.75
K	2.40	2.80
L	1.00	1.40
M	2.20	2.60
N	6.90	7.30
O	4.80	5.20
P	1.10	1.60
Q	6.00	6.40
R	1.00	1.40
S	15.90	16.60
T	13.00	13.60
U	4.90	5.30
V	2.30	2.70
W	2.30	2.70
X	0.70	1.10
Y	12.50	13.10
Z	7.70	8.30